







S3D03065A/S3D03065F/S3D03065E/S3D03065I 3A 650V SIC POWER SCHOTTKY RECTIFIERS

Description

This 650V 3A diode is high voltage Schottky rectifier that has very low total conduction losses and very stable switching characteristics over temperature extremes. The

S3D03065A/S3D03065F/S3D03065E/S3D03065I are ideal for energy sensitive, high frequency applications in challenging environments.

Applications

- Alternative energy inverters
- Power Factor Correction (PFC)
- Free-Wheeling diodes
- Switching supply output rectification
- Reverse polarity protection

Features

- 175°C T_J operation
- Ultra-low switching loss
- · Switching speeds independent of operating temperature
- Low total conduction losses
- High forward surge current capability
- High package isolation voltage
- Terminals finish: 100% Pure Tin
- "-A" is an AEC-Q101 qualified device
- Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

S3D03065A	S3D03065F	S3D03065E	S3D03065I
1 2 R	1 2 K.	к к 1	1 2
TO-220AC	ITO-220AC	DPAK	TO-220-Isolation
(TO-220-2)	(TO-220-F2)	(TO-252-2)	
PIN 1 (. ⊢0 K		PIN 1 O K







Maximum Ratings@T_A=25°C unless otherwise specified

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{DC}	-	650	V
	I _{F (AV)1}	Tc=25°C	17	А
Average Rectified Forward Current	I _{F (AV)2}	Tc=135°C	8	Α
	I _{F (AV)3}	Tc=165°C	3	Α
	I _{FRM1}	10ms, Half Sine pulse, Tc=25°C	16	Α
Repetitive Peak Forward Surge Current	I _{FRM2}	10ms, Half Sine pulse, Tc=110°C	14	Α
	I _{FSM1}	10ms, Half Sine pulse, Tc=25°C	27	Α
Peak One Cycle Non-Repetitive Surge Current	I _{FSM2}	10ms, Half Sine pulse, Tc=110°C	25	А
Non Popolitive Pook Forward Surge Current	I _{F,Max1}	10µs. Pulse, Tc =25℃	390	Α
Non-Repetitive Peak Forward Surge Current	I _{F,Max2}	10μs. Pulse, Tc=110°C	265	Α
.	P _{tot1}	Tc =25°C	89	W
Power Dissipation	P _{tot2}	Tc=110°C	39	W
		M3 Screw	1	Nm
TO-220 Mounting Torque		6-32 Screw	8.8	bf-in

Electrical Characteristics@T_A=25°C unless otherwise specified

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V _{F1}	@ 3A, Pulse, T _J = 25 °C	1.4	1.7	V
	V_{F2}	@ 3A, Pulse, T _J = 175 °C	1.6	2.0	V
Reverse Current*	I _{R1}	$@V_R = \text{rated } V_R$ $T_J = 25 ^{\circ}\text{C}$	0.03	2	uA
	I _{R2}	$@V_R = \text{rated } V_R$ $T_J = 175 ^{\circ}\text{C}$	0.3	20	uA
Junction Capacitance	Ст	V _R =0V, T _J =25℃, f=1MHz	230	-	pF
Reverse Recovery Charge	Qc	I _F = 3A, di/dt = 200A/μs VR = 400 V, T _J =25°C	14.35	-	nC
Capacitance Stored Energy	Ec	VR = 400 V, T _J =25°C	3.51	-	μJ

 $^{^{\}star}\,$ Pulse width < 300 $\mu s,\,$ duty cycle < 2%







Thermal-Mechanical Specifications@T_A=25°C unless otherwise specified

Characteristics	Symbol	S3D03065A	S3D03065F	S3D03065E	S3D03065I	Units
Junction Temperature	TJ		-55 to +175			°C
Storage Temperature	T _{stg}		-55 to +175			°C
Typical Thermal Resistance Junction to Case	R _{eJC}	1.7	4	1.5	3.3	°C/W

Ordering Information

Device	Package	Shipping
S3D03065A	TO-220AC(TO-220-2)	50pcs / tube
S3D03065F	ITO-220AC(TO-220-F2)	50pcs / tube
S3D03065E	DPAK(TO-252-2)	2500pcs / reel
S3D03065ETR	DPAK(TO-252-2)	2500pcs / reel
S3D03065I	TO-220-Isolation	50pcs / tube
S3D03065A-A	TO-220AC(TO-220-2)	50pcs / tube
S3D03065F-A	ITO-220AC(TO-220-F2)	50pcs / tube
S3D03065E-A	DPAK(TO-252-2)	2500pcs / reel
S3D03065I-A	TO-220-Isolation	50pcs / tube

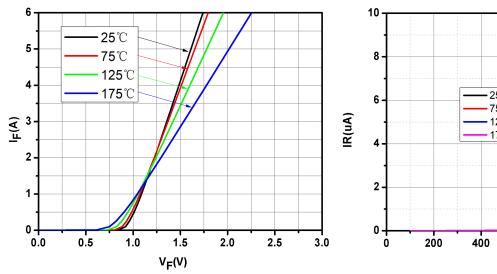
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.







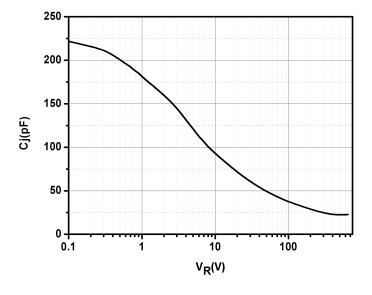
Ratings and Characteristics Curves

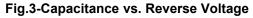


8625°C
75°C
125°C
125°C
175°C
17

Fig.1-Typical Forward Voltage Characteristics

Fig.2-Typical Reverse Characteristics





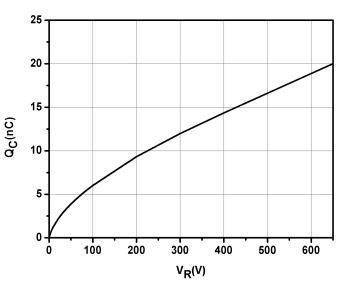


Fig.4-Total Capacitance Charge vs. Reverse Voltage







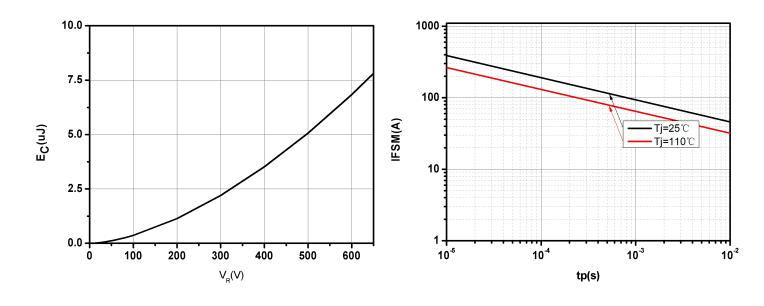


Fig.5-Capacitance Stored Energy

Fig.6-Non-repetitive peak forward surge current versus pulse duration (sinusoidal waveform)

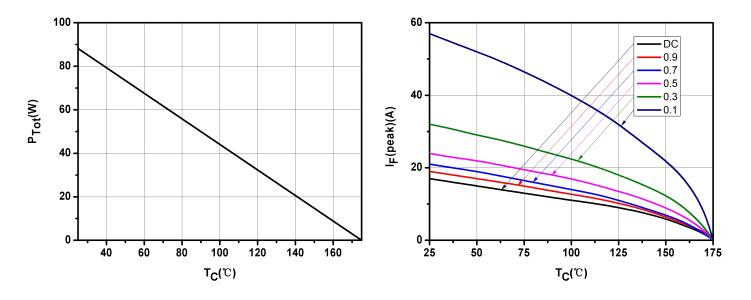


Fig.7-Power Derating

Fig.8-Current Derating

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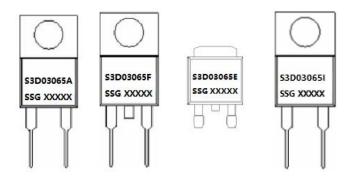
[•] http://www.smc-diodes.com - sales@ smc-diodes.com •







Marking Diagram



Where XXXXX is YYWWL

S3D = Device Type A/F/E/I = Package type 03 = Forward Current (3A) 065 = Reverse Voltage (650V)

 SSG
 = SSG

 YY
 = Year

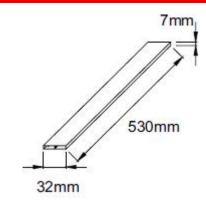
 WW
 = Week

 L
 = Lot Number

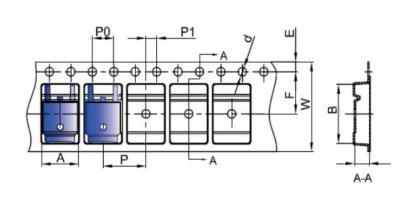
Cautions: Molding resin

Epoxy resin UL:94V-0

Tube Specification(TO-220-2/TO-220-F2/TO-220-Isolation)



Carrier Tape & Reel Specification DPAK(TO-252-2)



SYMBOL	Millimet	ters
STWBOL	Min.	Max.
Α	6.80	7.00
В	10.40	10.60
С	2.60	2.80
d	Ф1.45	Ф1.65
E	1.65	1.85
F	7.40	7.60
P0	3.90	4.10
Р	7.90	8.10
P1	1.90	2.10
W	15.90	16.30

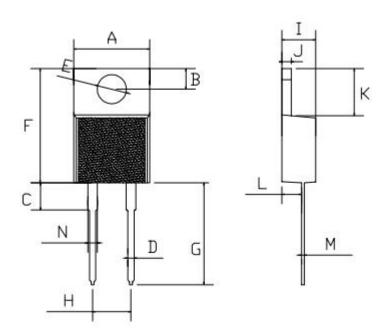
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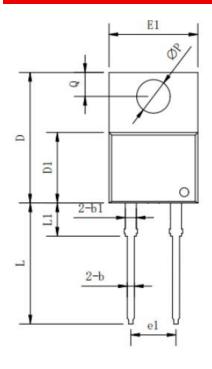


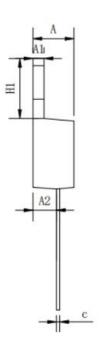
Mechanical Dimensions TO-220-Isolation



Symbol	Dimensions in millimeters			
•	Min.	Typical	Max.	
Α	9.7	-	10.4	
В	2.5	-	3	
С	3.5	-	3.9	
D	0.7	-	0.92	
E	3.72	-	3.95	
F	14.51	-	15.55	
G	12.95	-	13.9	
Н	4.95	-	5.19	
I	4.38	-	4.65	
J	1.15	-	1.36	
K	5.86	-	6.38	
L	2.35	-	2.85	
M	0.32	-	0.58	
N	1.18	-	1.42	

Mechanical Dimensions TO-220AC(TO-220-2)





Symbol	Dimensions in millimeters		
	Min.	Typical	Max.
А	3.56	-	4.83
A1	0.51	-	1.40
A2	2.03	-	2.92
b	0.38	-	1.02
b1	1.14	-	1.78
С	0.31	-	0.61
D	14.22	-	16.51
D1	8.38	-	9.42
E1	9.65	10.16	10.67
e1	-	5.08	-
H1	5.84	-	6.86
L	12.70	-	14.73
L1	-	-	6.35
ФР	-	3.56	-

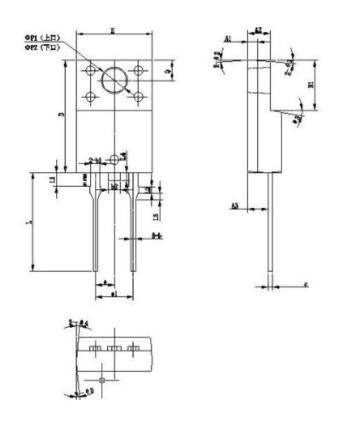
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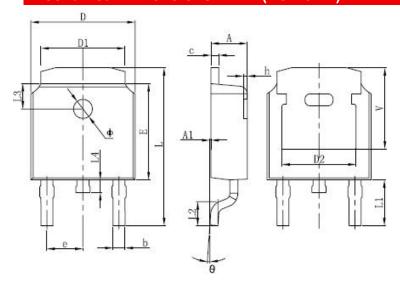


Mechanical Dimensions ITO-220AC(TO-220-2F)



Cumbal	Dimensions in millimeters			
Symbol	Min.	Typical	Max.	
Α	4.30	4.0	4.70	
A1		1.30		
A2	2.80	3.00	3.20	
A3	2.50	2.70	2.90	
b	0.5	0.6	0.75	
b1		1.20		
b2		1.60		
е	0.55	0.6	0.75	
D	14.80	15.00	15.20	
E	8.96	10.14	10.36	
е		2.55		
e1		5.10		
H1	8.50	8.70	8.90	
L	17.70	18.20	18.70	
L1		1.80		
L2		1.00		
L3		0.80		
L4		1.10		
ФР1(上口)	3.30	3.50	3.70	
ΦP1 (下口)	2.99	3.19	3.39	
Q	2.50	2.70	2.90	
Θ1		5°		
Θ2		4°		
Θ3		10°		
Θ4		5°		
Θ5		5°		

Mechanical Dimensions DPAK(TO-252-2)



SYMBOL	Dimensions in millimeters			
STWIBOL	Min.	Тур.	Max.	
Α	2.18	-	2.39	
A1	-	-	0.13	
b	0.64	-	0.89	
С	0.46	-	0.89	
D	6.35	-	6.73	
D1	4.95	-	5.46	
D2	4.32	-	-	
Е	5.97	6.1	6.22	
е		2.29BSC		
L	9.4	-	10.41	
L1		2.90 REF.		
L2	1.4	1.52	1.78	
L3		1.60 REF.		
L4	-	-	1.02	
Ф	1.1	-	1.3	
Θ	0°	-	10°	
V	5.21	_	_	

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